Customer No.: 31561 Application No.: 10/708,368 Docket No.: 10872-US-PA

## **AMENDMENT**

## In the Claims:

1. (original) An active-matrix organic electroluminescent (OEL) display panel, comprising:

a substrate;

a transparent conductive layer on the substrate;

a first passivation layer on the transparent conductive layer, having a plurality of openings therein exposing portions of the transparent conductive layer, wherein each opening defines a pixel region;

a plurality of thin film transistors arranged as a matrix, each comprising a gate electrode, a source and a drain disposed on the first passivation layer corresponding to an opening;

a plurality of organic function layers disposed on the transparent conductive layer in the openings; and

a plurality of metal electrode layers disposed on the organic function layers and electrically connected to the corresponding drains.

- 2. (original) The active-matrix OEL display panel of claim 1, wherein each organic function layer comprises a hole injection layer, a hole transporting layer, an emitting layer and an electron transporting layer that are stacked sequentially.
- 3. (original)The active-matrix OEL display panel of claim 1, further comprising a second passivation layer disposed on each thin film transistor.

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4. (original)The active-matrix OEL display panel of claim 1, wherein the transparent conductive layer includes indium tin oxide (ITO) or indium zinc oxide (IZO).

5. (original)The active-matrix OEL display panel of claim 1, wherein each metal electrode layer includes a LiF/Al composite layer.

6. (original)An active-matrix organic electroluminescent (OEL) display panel, comprising:

a substrate;

a metal layer on the substrate, having a plurality of opening therein exposing portions of the substrate;

a first passivation layer on the metal layer, having a plurality of openings therein aligned with the openings in the metal layer;

a plurality of thin film transistors arranged as a matrix, each comprising a gate electrode, a source and a drain and disposed on the first passivation layer corresponding to an opening;

a plurality of transparent conductive layers disposed on the substrate in the openings;

a plurality of organic function layers disposed on the transparent conductive layers in the openings; and

a plurality of metal electrode layers disposed on the organic function layers and electrically connected to the corresponding drains.

7. (original)The active-matrix OEL display panel of claim 6, wherein each organic function layer comprises a hole injection layer, a hole transporting layer, an emitting layer

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and an electron transporting layer.

8. (original) The active-matrix OEL display panel of claim 6, further comprising a second passivation layer on the thin film transistors.

- 9. (original)The active-matrix OEL display panel of claim 6, wherein the transparent conductive layer contains indium tin oxide (ITO) or indium zinc oxide (IZO).
- 10. (original)The active-matrix OEL display panel of claim 6, wherein the metal electrode layer includes a LiF/Al composite layer.

Claims 11-19 (cancelled)